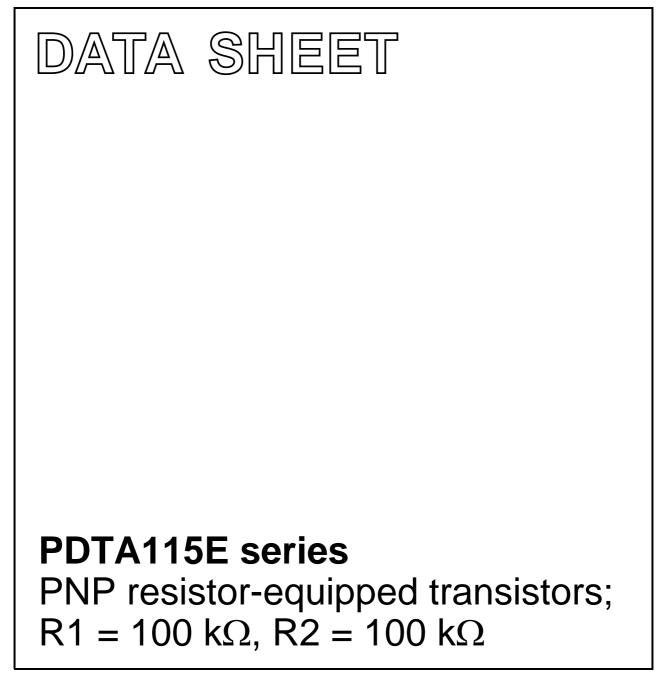
DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 2004 May 05 2004 Jul 30



### **PDTA115E series**

#### FEATURES

- Built-in bias resistors
- Simplified circuit design
- Reduction of component count
- Reduced pick and place costs.

#### APPLICATIONS

- General purpose switching and amplification
- Inverter and interface circuits
- Circuit driver.

**PRODUCT OVERVIEW** 

#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V <sub>CEO</sub>	collector-emitter voltage	-	-50	V
lo	output current (DC)	-	-20	mA
R1	bias resistor	100	-	kΩ
R2	bias resistor	100	-	kΩ

#### DESCRIPTION

PNP resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

TYPE NUMBER	PACKAGE			NPN COMPLEMENT	
	PHILIPS	EIAJ	MARKING CODE		
PDTA115EE	SOT416	SC-75	5E	PDTC115EE	
PDTA115EEF	SOT490	SC-89	6B	PDTC115EEF	
PDTA115EK	SOT346	SC-59	62	PDTC115EK	
PDTA115EM	SOT883	SC-101	F6	PDTC115EM	
PDTA115ES	SOT54 (TO-92)	SC-43	TA115E	PDTC115ES	
PDTA115ET	SOT23	_	*AB <sup>(1)</sup>	PDTC115ET	
PDTA115EU	SOT323	SC-70	*7C <sup>(1)</sup>	PDTC115EU	

#### Note

- 1. \* = p: Made in Hong Kong.
  - \* = t: Made in Malaysia.
  - \* = W: Made in China.

## PDTA115E series

#### SIMPLIFIED OUTLINE, SYMBOL AND PINNING

	BER SIMPLIFIED OUTLINE AND SYMBOL		PINNING		
TYPE NUMBER			DESCRIPTION		
PDTA115ES	$ \begin{array}{c} 1 \\ 2 \\ 3 \end{array} $ $ \begin{array}{c} 1 \\ 1 \\ 2 \\ 3 \end{array} $ $ \begin{array}{c} 1 \\ 1 \\ 1 \\ 1 \\ 1 \end{array} $ $ \begin{array}{c} 1 \\ 1 \\ 1 \\ 1 \\ 1 \end{array} $ $ \begin{array}{c} 1 \\ 1 \\ 1 \\ 1 \\ 1 \end{array} $ $ \begin{array}{c} 1 \\ 1 \\ 1 \\ 1 \\ 1 \end{array} $ $ \begin{array}{c} 1 \\ 1 \\ 1 \\ 1 \\ 1 \end{array} $ $ \begin{array}{c} 1 \\ 1 \\ 1 \\ 1 \\ 1 \end{array} $ $ \begin{array}{c} 1 \\ 1 \\ 1 \\ 1 \\ 1 \end{array} $ $ \begin{array}{c} 1 \\ 1 \\ 1 \\ 1 \\ 1 \end{array} $ $ \begin{array}{c} 1 \\ 1 \\ 1 \\ 1 \\ 1 \end{array} $ $ \begin{array}{c} 1 \\ 1 \\ 1 \\ 1 \\ 1 \\ 1 \end{array} $ $ \begin{array}{c} 1 \\ 1 \\ 1 \\ 1 \\ 1 \\ 1 \\ 1 \\ 1 \\ 1 \\ 1 \\$	PIN 1 2 3	base collector emitter		
PDTA115EE PDTA115EEF PDTA115EK PDTA115ET PDTA115EU	$\begin{array}{c} 3 \\ 1 \\ 1 \\ Top view \end{array}$	1 2 3	base emitter collector		
PDTA115EM	2 1 Bottom view Bottom view MDB267	1 2 3	base emitter collector		

## PDTA115E series

#### **ORDERING INFORMATION**

	PACKAGE			
TYPE NUMBER	NAME	DESCRIPTION	VERSION	
PDTA115EE	_	plastic surface mounted package; 3 leads	SOT416	
PDTA115EEF	<ul> <li>plastic surface mounted package; 3 leads</li> <li>S</li> </ul>		SOT490	
PDTA115EK	<ul> <li>plastic surface mounted package; 3 leads</li> <li>SC</li> </ul>		SOT346	
PDTA115EM	$- \qquad \  \  \  \  \  \  \  \  \  \  \  \  \$		SOT883	
PDTA115ES	<ul> <li>plastic single-ended leaded (through hole) package; 3 leads</li> </ul>		SOT54	
PDTA115ET	_	plastic surface mounted package; 3 leads	SOT23	
PDTA115EU	<ul> <li>plastic surface mounted package; 3 leads</li> <li>SOT</li> </ul>		SOT323	

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	—	-10	V
VI	input voltage				
	positive		—	+10	V
	negative		—	-40	V
I <sub>O</sub>	output current (DC)		-	-20	mA
I <sub>CM</sub>	peak collector current		-	-100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	SOT23	note 1	-	250	mW
	SOT54	note 1	—	500	mW
	SOT323	note 1	—	200	mW
	SOT346	note 1	-	250	mW
	SOT416	note 1	-	150	mW
	SOT490	notes 1 and 2	-	250	mW
	SOT883	notes 2 and 3	_	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60  $\mu$ m copper strip line.

## PDTA115E series

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	$T_{amb} \le 25 \ ^{\circ}C$		
	SOT23	note 1	500	K/W
	SOT54	note 1	250	K/W
	SOT323	note 1	625	K/W
	SOT346	note 1	500	K/W
	SOT416	note 1	833	K/W
	SOT490	notes 1 and 2	500	K/W
	SOT883	notes 2 and 3	500	K/W

#### Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60  $\mu$ m copper strip line.

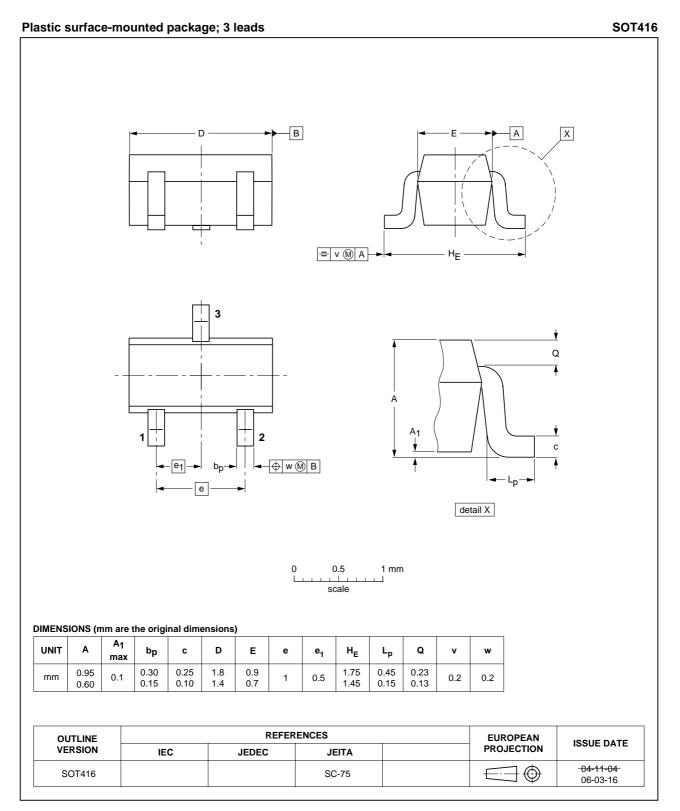
#### CHARACTERISTICS

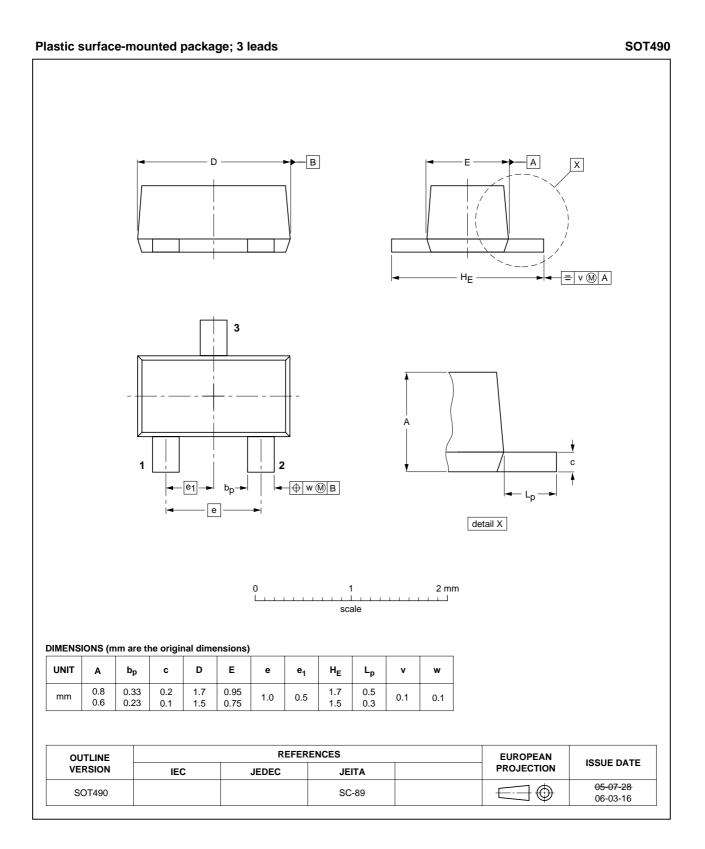
 $T_{amb}$  = 25 °C unless otherwise specified.

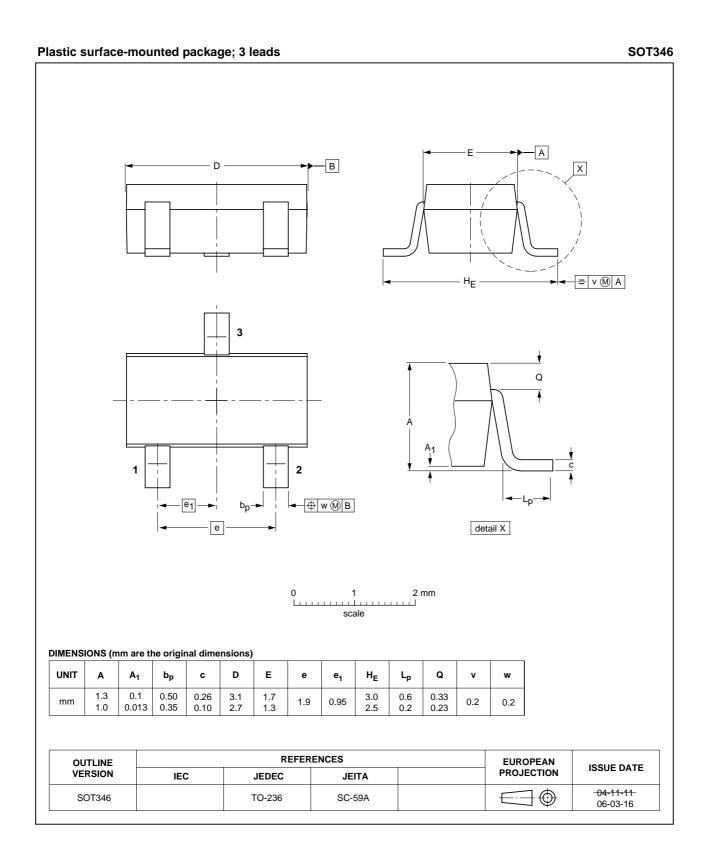
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	_	_	-100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE} = -30 \text{ V}; \text{ I}_{B} = 0 \text{ A}$	-	_	-1	μA
		V <sub>CE</sub> = -30 V; I <sub>B</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	-50	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	_	_	-50	μA
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -5 \text{ mA}$	80	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C} = -5 \text{ mA}; I_{B} = -0.25 \text{ mA}$	-	-	-150	mV
V <sub>i(off)</sub>	input-off voltage	$I_C = -100 \ \mu\text{A}; \ V_{CE} = -5 \ V$	-	-1.2	-0.5	V
V <sub>i(on)</sub>	input-on voltage	$I_{C} = -1 \text{ mA}; V_{CE} = -0.3 \text{ V}$	-3	-1.6	-	V
R1	input resistor		70	100	130	kΩ
<u>R2</u> R1	resistor ratio		0.8	1	1.2	
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0 \text{ A}; V_{CB} = -10 \text{ V};$ f = 1 MHz	-	_	3	pF

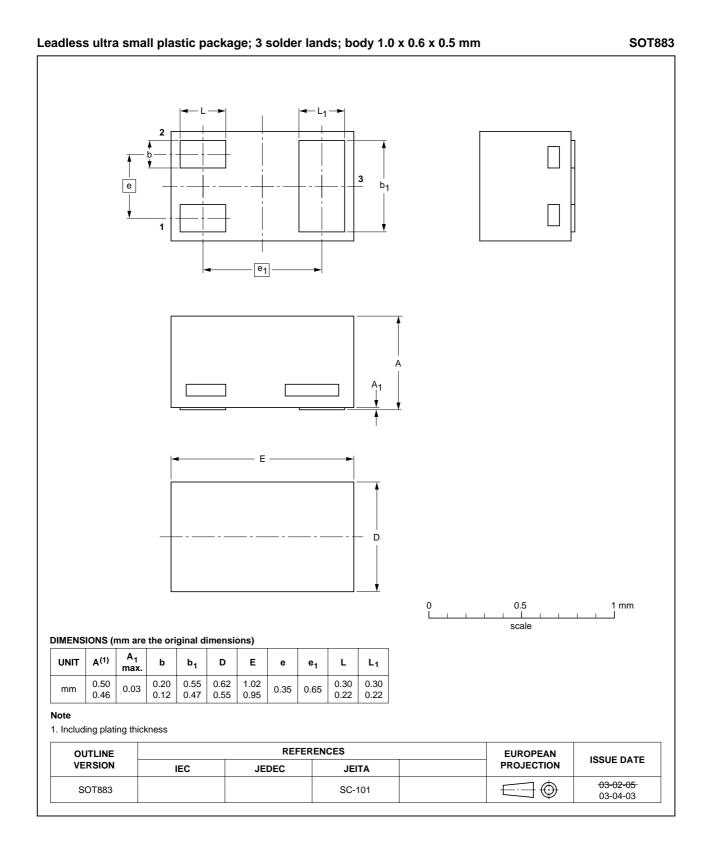
## PDTA115E series

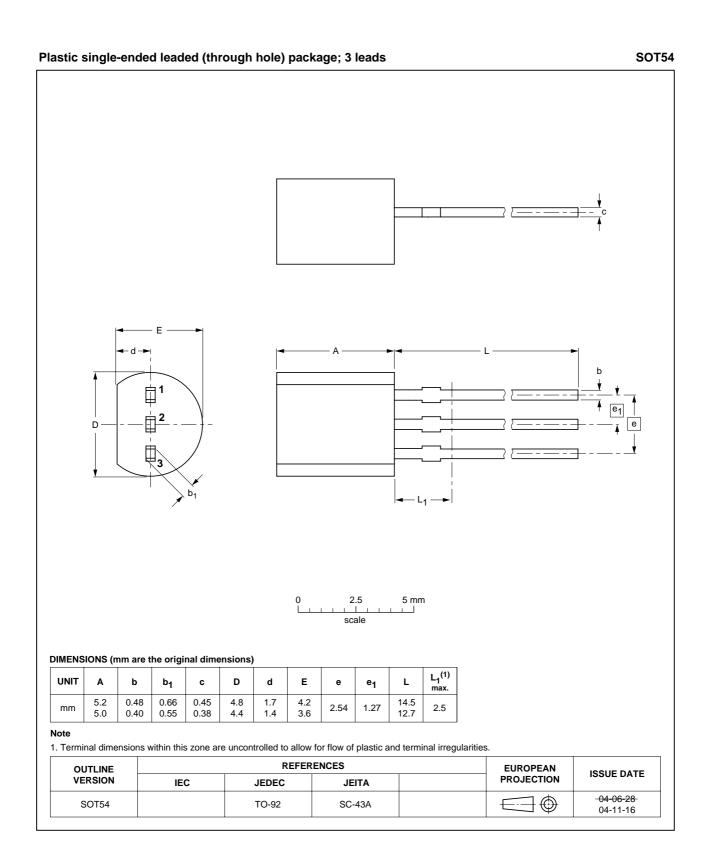
#### PACKAGE OUTLINES

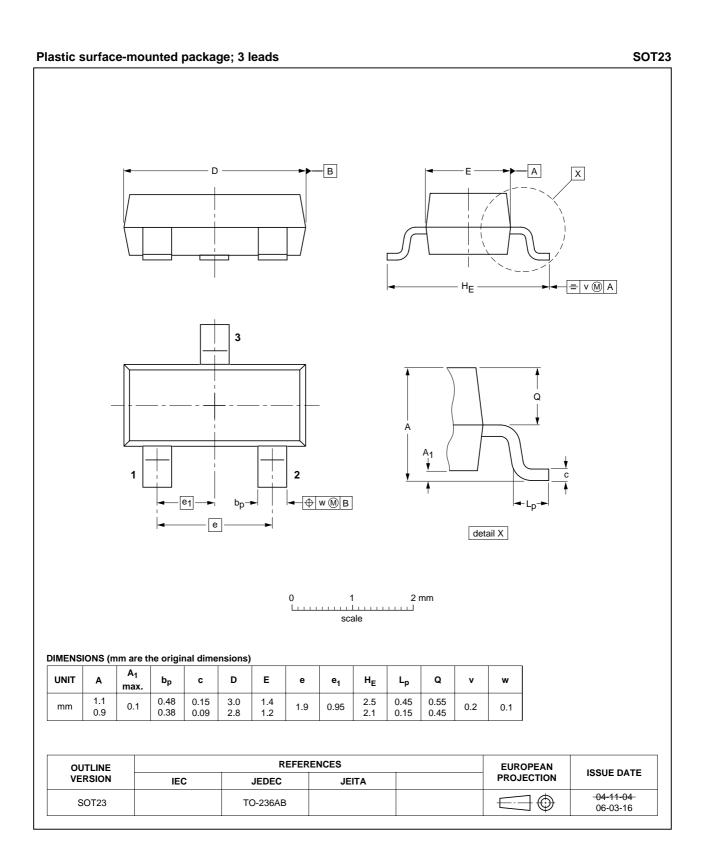


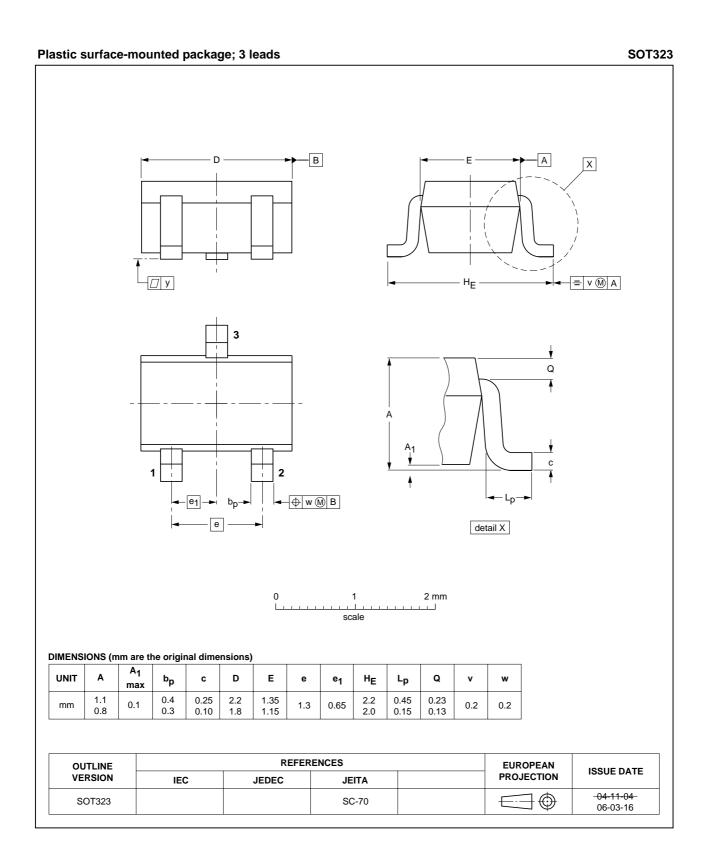












### PDTA115E series

#### DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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#### **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

#### **Contact information**

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